#### PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	SECURITY INTEREST

#### **CONVEYING PARTY DATA**

Name	Execution Date
WESTERN DIGITAL TECHNOLOGIES, INC.	05/11/2020

#### **RECEIVING PARTY DATA**

Name:	JPMORGAN CHASE BANK, N.A., AS AGENT
Street Address:	IL1-1145/54/63, P.O. BOX 6026
City:	CHICAGO
State/Country:	ILLINOIS
Postal Code:	60680

#### **PROPERTY NUMBERS Total: 163**

Property Type	Number
Patent Number:	10636442
Patent Number:	10553241
Application Number:	16780281
Application Number:	16780216
Application Number:	16781885
Application Number:	16781194
Application Number:	16781216
Application Number:	16781717
Application Number:	16781688
Application Number:	16781225
Application Number:	16783057
Application Number:	16784077
Application Number:	16786889
Application Number:	16787482
Application Number:	16787859
Application Number:	16788117
Application Number:	62975661
Application Number:	16792060
Application Number:	16791759
Application Number:	16791560

PATENT REEL: 053482 FRAME: 0453

506060833

Property Type	Number
Application Number:	16791238
Application Number:	16792010
Application Number:	16794079
Application Number:	16794100
Application Number:	16799757
Application Number:	16798650
Application Number:	16798590
Application Number:	16798682
Application Number:	16801921
Application Number:	16801375
Application Number:	16803952
Application Number:	16803960
Application Number:	16803962
Application Number:	16803958
Application Number:	16803851
Application Number:	16802638
Application Number:	16805244
Application Number:	16805403
Application Number:	16805414
Application Number:	16805570
Application Number:	16805574
Application Number:	16806029
Application Number:	16808656
Application Number:	16811816
Application Number:	16812549
Application Number:	16814761
Application Number:	16814812
Application Number:	16814864
Application Number:	62987831
Application Number:	16814631
Application Number:	16816211
Application Number:	16815416
Application Number:	16815860
Application Number:	29727700
Application Number:	16817264
Application Number:	16817138
Application Number:	16818817
Application Number:	16818752

Property Type	Number
Application Number:	16818290
Application Number:	16818883
Application Number:	16818426
Application Number:	16818949
Application Number:	16818571
Application Number:	16818452
Application Number:	16820552
Application Number:	16819636
Application Number:	16821860
Application Number:	16821918
Application Number:	16821926
Application Number:	16821849
Application Number:	16820711
Application Number:	16823235
Application Number:	16823185
Application Number:	16822010
Application Number:	16824508
Application Number:	16824581
Application Number:	16824587
Application Number:	16824519
Application Number:	16824584
Application Number:	16824269
Application Number:	16823592
Application Number:	16824514
Application Number:	16823714
Application Number:	16826063
Application Number:	16824814
Application Number:	16825762
Application Number:	16825836
Application Number:	16827605
Application Number:	16827597
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Application Number:	16828901
Application Number:	16828953
Application Number:	16828948
Application Number:	16828945

Property Type	Number
Application Number:	16828532
Application Number:	16829792
Application Number:	16830222
Application Number:	16830129
Application Number:	16830167
Application Number:	16831004
Application Number:	16830612
Application Number:	16831729
Application Number:	16831728
Application Number:	16831517
Application Number:	16833310
Application Number:	16832402
Application Number:	16832352
Application Number:	16833650
Application Number:	16835198
Application Number:	16833942
Application Number:	16835191
Application Number:	16835016
Application Number:	16834515
Application Number:	16834403
Application Number:	16836687
Application Number:	16836764
Application Number:	16836730
Application Number:	16835837
Application Number:	16835836
Application Number:	16836679
Application Number:	16836454
Application Number:	16836424
Application Number:	16837313
Application Number:	16837786
Application Number:	16837889
Application Number:	16845685
Application Number:	16847352
Application Number:	16848700
Application Number:	16851568
Application Number:	16852091
Application Number:	16851510
Application Number:	16851574

Property Type	Number
Application Number:	16852462
Application Number:	16853275
Application Number:	16853408
Application Number:	16853233
Application Number:	16853407
Application Number:	63013236
Application Number:	16854677
Application Number:	16855549
Application Number:	16857053
Application Number:	16857423
Application Number:	16858332
Application Number:	16858339
Application Number:	16858345
Application Number:	16858350
Application Number:	16858356
Application Number:	16858358
Application Number:	16858390
Application Number:	16858223
Application Number:	16858265
Application Number:	16858318
Application Number:	16859940
Application Number:	16859494
Application Number:	16861118
Application Number:	16861068
Application Number:	16860720
Application Number:	16853440
Application Number:	16861543
Application Number:	16861565
Application Number:	16731672

#### **CORRESPONDENCE DATA**

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NAME OF SUBMITTER:	MICHELLE DELOS ANGELES	
SIGNATURE:	/Michelle Delos Angeles/	
DATE SIGNED:	05/14/2020	
Total Attachments: 10		
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Execution Version

#### Patent Collateral Agreement

This Monday, May 11, 2020, WESTERN DIGITAL TECHNOLOGIES, INC. ("Debtor"), for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, grants to JPMORGAN CHASE BANK, N.A., a national banking association (the "Agent"), acting as collateral agent hereunder for the Secured Parties as defined in the Security Agreement, dated as of May 12, 2016, among Debtor, Agent and the other debtors party thereto, as the same may be amended, restated, amended and restated or otherwise modified from time to time (the "Security Agreement") for the benefit of the Secured Parties, a lien on and security interest in, all right, title, and interest of such Debtor in and to all of the following (collectively, "Patent Collateral"):

- (i) Each patent and patent application owned by Debtor, other than to the extent the same constitutes Excluded Property, that is listed on <u>Schedule A</u> hereto (the "*Patents*"); and
- (ii) All proceeds of the foregoing, including any claim by Debtor against third parties for damages by reason of past, present or future infringement of any Patent, in each case together with the right to sue for and collect said damages.

All capitalized terms used herein without definition have the meanings given to such terms in the Security Agreement.

Debtor and Agent do hereby further acknowledge and affirm that the rights and remedies of the Agent with respect to the grant of a security interest in the Patent Collateral made hereby are more fully set forth in, and subject to, the Security Agreement, the terms and provisions of which are incorporated herein by reference as if fully set forth herein. In the event of any conflict between the terms of this Patent Collateral Agreement and the terms of the Security Agreement, the terms of the Security Agreement shall govern.

THIS PATENT COLLATERAL AGREEMENT AND THE RIGHTS AND OBLIGATIONS OF THE PARTIES HEREUNDER SHALL BE GOVERNED BY, AND CONSTRUED BY AND INTERPRETED IN ACCORDANCE WITH, THE LAW OF THE STATE OF NEW YORK.

[SIGNATURE PAGE TO FOLLOW]

IN WITNESS WHEREOF, Debtor has caused this Patent Collateral Agreement to be duly executed as of the date and year last above written.

WESTERN DIGITAL TECHNOLOGIES, INC., as Debtor

Michael Ray

Name: Michael Ray

Title: Executive Vice President,

Chief Legal Officer and Secretary

Accepted and agreed to as of the date and year last above written.

JPMORGAN CHASE BANK, N.A., as Agent

By:

Name:

Title:

### SCHEDULE A TO PATENT COLLATERAL AGREEMENT

[See Attached.]

nnnnnnnnnnn		Patent/App.
No.	Title	Number
1	Storage System and Method for Boundary Wordline Data Retention Handling	16/780,281
2	Storage System and Method for Host Memory Access	16/780,216
3	Dual SLC/QLC Programming and Resource Releasing	16/781,885
4	DATA STORAGE DEVICE MANAGING PEAK CURRENT FOR MULTIPLE ACTUATORS	16/781,194
	DATA STORAGE DEVICE SORTING ACCESS COMMANDS BASED ON PEAK CURRENT	16/781,216
5	FOR MULTIPLE ACTUATORS	- Separate S
6	Storage System and Method for Optimized Surveillance Search	16/781,717
7	Storage System and Method for Automatic Data Phasing	16/781,688
•••••	MAGNETIC DEVICE INCLUDING MULTIFERROIC REGIONS AND METHODS OF	16/781,225
8	FORMING THE SAME	-
9	MAGNETIC RECORDING WRITE HEAD WITH SPIN-TORQUE OSCILLATOR (STO) AND EXTENDED SEED LAYER	16/783,057
	TRAINING DATA SAMPLE SELECTION FOR USE WITH NON-VOLATILE MEMORY AND	16/784,077
10	MACHINE LEARNING PROCESSOR	PARTITION
11	Nand Dropped Command Detection And Recovery	16/786,889
12	THERMAL RELIEF FOR THROUGH-HOLE AND SURFACE MOUNTING	16/787,482
13	RESTRICTING ACCESS TO A DATA STORAGE SYSTEM ON A LOCAL NETWORK	16/787,859
14	METHOD AND SYSTEM FOR ADDRESS TABLE CACHE MANAGEMENT	16/788,117
************	BiSb Topological Insulator with Novel Buffer Layer that Promotes a BiSb (012)	62/975,661
15	Orientation	
***********	SPIN-TORQUE OSCILLATOR WITH MULTILAYER SEED LAYER BETWEEN THE WRITE	16/792,060
16	POLE AND THE FREE LAYER IN A MAGNETIC RECORDING WRITE HEAD	REPERENT
	SPIN TORQUE OSCILLATOR (STO) SENSORS USED IN NUCLEIC ACID SEQUENCING	16/791,759
	ARRAYS AND DETECTION SCHEMES FOR NUCLEIC ACID SEQUENCING	- PARAMETER PARA
17		AMARACA
18	STORAGE DEVICE WITH INCREASED ENDURANCE	16/791,560
	HEAT-ASSISTED MAGNETIC RECORDING (HAMR) DISK DRIVE WITH INTERFACE	16/791,238
19	VOLTAGE CONTROL CIRCUITRY	REPRESENTA
	TWO-DIMENSIONAL MAGNETIC RECORDING (TDMR) READ HEAD STRUCTURE	16/792,010
	WITH DIFFERENT STACKED SENSORS AND DISK DRIVE INCORPORATING THE	REPERENT
20	STRUCTURE	REPERENT
21	Load/Unload Ramp Mechanism For Reduced Cracking	16/794,079
22	Ultra-low RA and high TMR magnetic sensor with radiation reflective lead	16/794,100
23	DATA STORAGE DEVICE ADAPTOR WITH SECUREMENT MECHANISM	16/799,757
24	VARIABLE READ SCAN FOR SOLID-STATE STORAGE DEVICE QUALITY OF SERVICE	16/798,650
	DYNAMICALLY ADJUST DATA TRANSFER SPEED FOR NON-VOLATILE MEMORY DIE	16/798,590
25	INTERFACES	

30000000000000000000000000000000000000	U.S. PATENT REGISTRATION	ponnononononononono
	DATA STORAGE DEVICE BANK WRITING SERVO SECTORS FOR INTERLEAVED SERVO	16/798,682
26	CONTROL PROCESSING	***************************************
27	OFFSET SWAGE BASEPLATE FOR STACKED ASSEMBLY	16/801,921
28	DATA STORAGE DEVICE WITH SPREAD SPECTRUM SPINDLE MOTOR CONTROL	16/801,375
	SPIN TRANSFER TORQUE (STT) DEVICE WITH TEMPLATE LAYER FOR HEUSLER	16/803,952
29	ALLOY MAGNETIC LAYERS	
	SPIN TRANSFER TORQUE DEVICE WITH OXIDE LAYER BENEATH THE SEED LAYER	16/803,960
30		
31	AREAL DENSITY CAPABILITY IMPROVEMENT WITH A MAIN POLE SKIN	16/803,962
	SPIN-ORBIT TORQUE INDUCED MAGNETIZATION SWITCHING IN A MAGNETIC	16/803,958
32	RECORDING HEAD	
33	OBJECT DETECTION USING MULTIPLE NEURAL NETWORK CONFIGURATIONS	16/803,851
34	Data Storage With Improved Write Performance For Preferred User Data	16/802,638
35	Embedded PHY (EPHY) IP Core for FPGA	16/805,244
	HAMR Media To Assist Optically Transparent Build-Up On NFT To Improve	16/805,403
36	Reliability	
	In-situ NFT pre-treatment to accumulate optically transparent material on NFT to	16/805,414
37	improve reliability	
38	Data Storage With Improved Suspend Resume Performance	16/805,570
39	Data Storage With Improved Read Performance By Avoiding Line Discharge	16/805,574
40	CALIBRATING ELEVATOR ACTUATOR FOR DISK DRIVE	16/806,029
	DATA STORAGE DEVICE EMPLOYING STAGGERED SERVO WEDGES TO INCREASE	16/808,656
41	CAPACITY	
	MAGNETIC RECORDING HEAD WITH NON-MAGNETIC CONDUCTIVE STRUCTURE	16/811,816
42		
43	Data Storage Device With Improved Interface Transmitter Training	16/812,549
44	Semiconductor Device With Top Die Positioned To Reduce Die Cracking	16/814,761
45	Semiconductor Device Including Magnetic Hold-Down Layer	16/814,812
46	Semiconductor Device Including Contact Fingers On Opposed Surfaces	16/814,864
	MAGNETIC SENSOR ARRAYS FOR NUCLEIC ACID SEQUENCING AND METHODS OF	62/987,831
47	MAKING AND USING THEM	, ,
48	Cycle Borrowing Counter	16/814,631
***************************************	HIGH-BANDWIDTH STO BIAS ARCHITECTURE WITH INTEGRATED SLIDER VOLTAGE	16/816,211
49	POTENTIAL CONTROL	• • • • • • • • • • • • • • • • • • • •
***************************************	DATA STORAGE DEVICE EMPLOYING MULTI-LEVEL PARITY SECTORS FOR DATA	16/815,416
50	RECOVERY PROCEDURE	, -,
	Storage System and Method for Implementing an Encoder, Decoder, and/or Buffer	16/815.860
51	Using a Field Programmable Gate Array	,,
52	DATA STORAGE DEVICE	29/727,700
53	Snapshot management in partitioned storage	16/817,264
	DATA STORAGE DEVICE CONTROLLING HEAD FLY HEIGHT BASED ON	16/817,138
54	TEMPERATURE	
	1	

Therefrom   16/818,   Semiconductor Device Including Bifurcated Memory Module   16/818,   Semiconductor Device Including High Speed Heterogeneous Integrated Controller   16/818,   16/8		O.O. I ATERS INCOMINATION	
16/818,   Semiconductor Device Including Bifurcated Memory Module   16/818,   Semiconductor Device Including High Speed Heterogeneous Integrated Controller   16/818,   And Cache   16/818,   And Cache   16/818,   Semiconductor Device Including Vertically Stacked Semiconductor Dies   16/818,   Semiconductor Device Name State Device Name Name State Device Name Name State Device Name Name Name Name Name Name Name Nam		*	16/818,817
Semiconductor Device Including High Speed Heterogeneous Integrated Controller And Cache Semiconductor Device Including Vertically Stacked Semiconductor Dies Semiconductor Device Including Vertically Stacked Semiconductor Dies SEMICONDUCTOR DIE AND SEMICONDUCTOR PACKAGE METHODS AND SYSTEMS FOR IMPLEMENTING REDUNDANCY IN MEMORY CONTROLLERS Combined QLC Programming Method Storage System and Method for Improved Playback Analysis Storage System and Method for Improved Playback Analysis MEASUREMENT, CALIBRATION AND TUNING OF MEMORY BUS DUTY CYCLE DEVICES AND METHODS FOR FREQUENCY- AND PHASE-BASED DETECTION OF MAGNETICALLY-LABELED MOLECULES USING SPIN TORQUE OSCILLATOR (STO) SENSORS APERTURE STRUCTURE ON SEMICONDUCTOR COMPONENT BACKSIDE TO ALLEVIATE DELAMINATION IN STACKED PACKAGING EXTENSIBLE STORAGE SYSTEM AND METHOD SYSTEM AND METHOD SYSTEM AND METHODS FOR LOCATING A SAMPLE READ IN A REFERENCE GIONOME SOST-DECISION INPUT GENERATION FOR DATA STORAGE SYSTEMS TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE TO SUSTEMBUTION OF LOGICAL-TO-PHYSICAL ADDRESS ENTRIES ACROSS BANK TO SUST	55		***************************************
57 And Cache 58 Semiconductor Device Including Vertically Stacked Semiconductor Dies 59 SEMICONDUCTOR DIE AND SEMICONDUCTOR PACKAGE 59 SEMICONDUCTOR DIE AND SEMICONDUCTOR PACKAGE 50 METHODS AND SYSTEMS FOR IMPLEMENTING REDUNDANCY IN MEMORY 50 CONTROLLERS 61 Combined QLC Programming Method 62 Storage System and Method for Improved Playback Analysis 63 MEASUREMENT, CALIBRATION AND TUNING OF MEMORY BUS DUTY CYCLE 64 DEVICES AND METHODS FOR FREQUENCY- AND PHASE-BASED DETECTION OF 65 MAGNETICALLY-LABELED MOLECULES USING SPIN TORQUE OSCILLATOR (STO) 66 SENSORS 66 PARTURE STRUCTURE ON SEMICONDUCTOR COMPONENT BACKSIDE TO 67 ALLEVIATE DELAMINATION IN STACKED PACKAGING 67 EXTENSIBLE STORAGE SYSTEM AND METHOD 68 EXTENSIBLE STORAGE SYSTEM AND METHOD 69 SYSTEM and Method to Enhance Solder Joint Reliability 60 SYSTEM AND METHODS FOR LOCATING A SAMPLE READ IN A REFERENCE 61 GENOME 62 SOFT-DECISION INPUT GENERATION FOR DATA STORAGE SYSTEMS 63 TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE 64 AND METHODS FOR LOCATING DATA STORAGE SYSTEMS 65 SYSTEMS and Methods for Multi-Zone Data Tiering for Endurance Extension in Solid 66 SYSTEMS and Methods for Multi-Zone Data Tiering for Endurance Extension in Solid 67 SOFT-DECISION INPUT GENERATION FOR DATA STORAGE SYSTEMS 68 SYSTEMS and Methods for Multi-Zone Data Tiering for Endurance Extension in Solid 69 SOFT-DECISION INPUT GENERATION FOR DATA STORAGE SYSTEMS 70 STATE DIVISOR OF LOCATING DATA STORAGE SYSTEMS 71 PAGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE 72 REFERENCE-GUIDED GENOME SEQUENCING 73 STATE DIVISOR OF LOCATING DATA STORAGE SYSTEMS 74 MULTI-STREAM JOURNAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE 75 MULTI-STREAM JOURNAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE 76 DYNAMIC MULTI-STAGE DECODING 77 ADJUSTABLE READ RETRY ORDER BASED ON DECODING SUCCESS TREND 78 MAGNETIC GRADIENT CONCENTRATOR/RELUCTANCE DETECTOR FOR MOLECULE 79 DETECTION 80 SWAGE PLATE ASSEMBLY WITH SWAGE BOSS INSERT 81 Entropy Driven Endurance For Normalized Quality Of Service 81	56		16/818,752
58 Semiconductor Device Including Vertically Stacked Semiconductor Dies 16/818, 59 SEMICONDUCTOR DIE AND SEMICONDUCTOR PACKAGE 16/818, METHODS AND SYSTEMS FOR IMPLEMENTING REDUNDANCY IN MEMORY 16/818, 60 CONTROLLERS 16/818, METHODS AND SYSTEMS FOR IMPLEMENTING REDUNDANCY IN MEMORY 16/818, 60 Combined QLC Programming Method 16/818, 61 Combined QLC Programming Method 16/818, 62 Storage System and Method for Improved Playback Analysis 16/818, 63 MEASUREMENT, CALIBRATION AND TUNING OF MEMORY BUS DUTY CYCLE 16/820, DEVICES AND METHODS FOR FREQUENCY- AND PHASE-BASED DETECTION OF MAGNETICALLY-LABELED MOLECULES USING SPIN TORQUE OSCILLATOR (STO) SENSORS APERTURE STRUCTURE ON SEMICONDUCTOR COMPONENT BACKSIDE TO 16/821, 65 SUSTEMS AND METHOD 16/821, 66 EXTENSIBLE STORAGE SYSTEM AND METHOD 16/821, 67 System and Method to Enhance Solder Joint Reliability 16/821, 68 REFERENCE-GUIDED GENOME SEQUENCING 16/821, 16/820, 69 GENOME 16/821,		Semiconductor Device Including High Speed Heterogeneous Integrated Controller	16/818,290
59 SEMICONDUCTOR DIE AND SEMICONDUCTOR PACKAGE  METHODS AND SYSTEMS FOR IMPLEMENTING REDUNDANCY IN MEMORY  16/818, 60 CONTROLLERS  16/818, 61 Combined QLC Programming Method  16/818, 62 Storage System and Method for Improved Playback Analysis  16/818, 63 MEASUREMENT, CALIBRATION AND TUNING OF MEMORY BUS DUTY CYCLE  16/820, DEVICES AND METHODS FOR FREQUENCY- AND PHASE-BASED DETECTION OF MAGNETICALLY-LABELED MOLECULES USING SPIN TORQUE OSCILLATOR (STO)  SENSORS  APPERTURE STRUCTURE ON SEMICONDUCTOR COMPONENT BACKSIDE TO  ALLEVIATE DELAMINATION IN STACKED PACKAGING  EXTENSIBLE STORAGE SYSTEM AND METHOD  66 EXTENSIBLE STORAGE SYSTEM AND METHOD  57 System and Method to Enhance Solder Joint Reliability  68 REFERENCE-GUIDED GENOME SEQUENCING  69 DEVICES AND METHODS FOR LOCATING A SAMPLE READ IN A REFERENCE  69 GENOME  70 SOFT-DECISION INPUT GENERATION FOR DATA STORAGE SYSTEMS  71 TANGENTIAL AND LONGITUDINAL GLIDE RAMP FOR MAGNETIC STORAGE DEVICE  72 REFERENCE-GUIDED GENOME SEQUENCING  Systems and Methods for Multi-Zone Data Tiering for Endurance Extension in Solid  16/824, 73 State Drives  74 Multi-Stream Journaled Replay  DISTRIBUTION OF LOGICAL-TO-PHYSICAL ADDRESS ENTRIES ACROSS BANK  16/824, 75 GROUPS  76 DYNAMIC MULTI-STAGE DECODING  77 ADJUSTABLE READ RETRY ORDER BASED ON DECODING SUCCESS TREND  16/824, 77 MAGNETIC GRADIENT CONCENTRATOR/RELUCTANCE DETECTOR FOR MOLECULE  16/823, 16/824, 16/826,	57		
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